



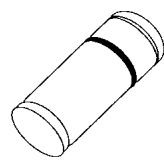
**TMMBAT 47**  
**TMMBAT 48**

## SMALL SIGNAL SCHOTTKY DIODES

### DESCRIPTION

General purpose, metal to silicon diodes featuring very low turn-on voltage and fast switching. These devices have integrated protection against excessive voltage such as electrostatic discharges.

**MINIMELF**  
(Glass)



### ABSOLUTE RATINGS (limiting values)

Symbol	Parameter		TMMBAT47	TMMBAT48	Unit
$V_{RRM}$	Repetitive Peak Reverse Voltage		20	40	V
$I_F$	Forward Continuous Current		$T_I = 25^\circ\text{C}$		350 mA
$I_{FRM}$	Repetitive Peak Forward Current		$t_p \leq 1\text{s}$ $\delta \leq 0.5$	1	A
$I_{FSM}$	Surge non Repetitive Forward Current		$t_p = 10\text{ms}$	7.5	A
			$t_p = 1\text{s}$	1.5	
$P_{tot}$	Power Dissipation		$T_I = 25^\circ\text{C}$	330	mW
$T_{stg}$ $T_j$	Storage and Junction Temperature Range		- 65 to 150 - 65 to 125		$^\circ\text{C}$ $^\circ\text{C}$
$T_L$	Maximum Temperature for Soldering during 15s		260		$^\circ\text{C}$

### THERMAL RESISTANCE

Symbol	Test Conditions	Value	Unit
$R_{th(j-l)}$	Junction-leads	300	$^\circ\text{C/W}$

## TMMBAT 47/TMMBAT 48

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### ELECTRICAL CHARACTERISTICS

#### STATIC CHARACTERISTICS

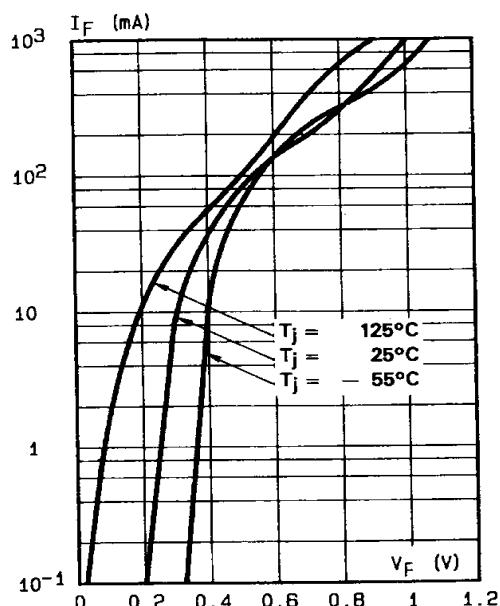
Symbol	Test Conditions		Min.	Typ.	Max.	Unit
$V_{BR}$	$T_j = 25^\circ C$	$I_R = 10\mu A$	TMMBAT47	20		V
	$T_j = 25^\circ C$	$I_R = 25\mu A$	TMMBAT48	40		
$V_F^*$	$T_j = 25^\circ C$	$I_F = 0.1mA$	All Types		0.25	V
	$T_j = 25^\circ C$	$I_F = 1mA$			0.3	
	$T_j = 25^\circ C$	$I_F = 10mA$			0.4	
	$T_j = 25^\circ C$	$I_F = 30mA$	TMMBAT47		0.5	
	$T_j = 25^\circ C$	$I_F = 150mA$			0.8	
	$T_j = 25^\circ C$	$I_F = 300mA$			1	
	$T_j = 25^\circ C$	$I_F = 50mA$	TMMBAT48		0.5	
	$T_j = 25^\circ C$	$I_F = 200mA$			0.75	
	$T_j = 25^\circ C$	$I_F = 500mA$			0.9	
$I_R^*$	$T_j = 25^\circ C$	$V_R = 1.5V$	All Types		1	$\mu A$
	$T_j = 60^\circ C$				10	
	$T_j = 25^\circ C$	$V_R = 10V$	TMMBAT47		4	
	$T_j = 60^\circ C$				20	
	$T_j = 25^\circ C$	$V_R = 20V$			10	
	$T_j = 60^\circ C$				30	
	$T_j = 25^\circ C$	$V_R = 10V$	TMMBAT48		2	
	$T_j = 60^\circ C$				15	
	$T_j = 25^\circ C$	$V_R = 20V$			5	
	$T_j = 60^\circ C$				25	
	$T_j = 25^\circ C$	$V_R = 40V$			25	
	$T_j = 60^\circ C$				50	

#### DYNAMIC CHARACTERISTICS

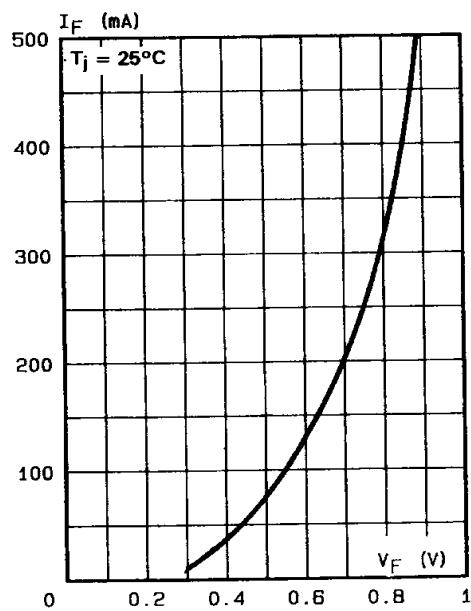
Symbol	Test Conditions			Min.	Typ.	Max.	Unit
C	$T_j = 25^\circ C$	$V_R = 0V$	$f = 1MHz$		20		$pF$
	$T_j = 25^\circ C$	$V_R = 1V$			12		
$t_{rr}$	$T_j = 25^\circ C$	$I_F = 10mA$	$V_R = 1V$	$i_{rr} = 1mA$	$R_L = 100\Omega$		ns

\* Pulse test:  $t_p \leq 300\mu s$   $\delta < 2\%$ .

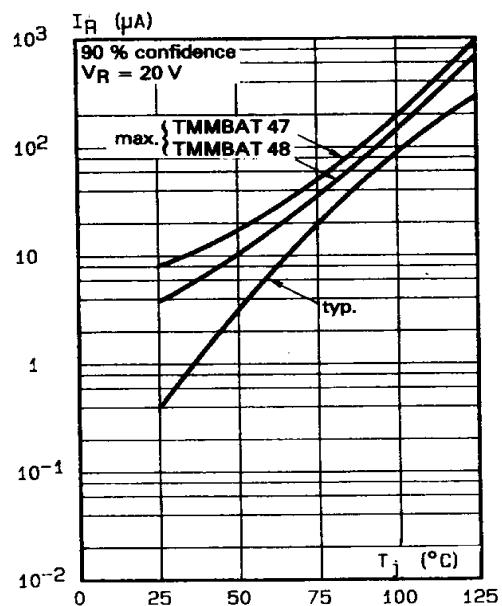
**Figure 1.** Forward current versus forward voltage at different temperatures (typical values).



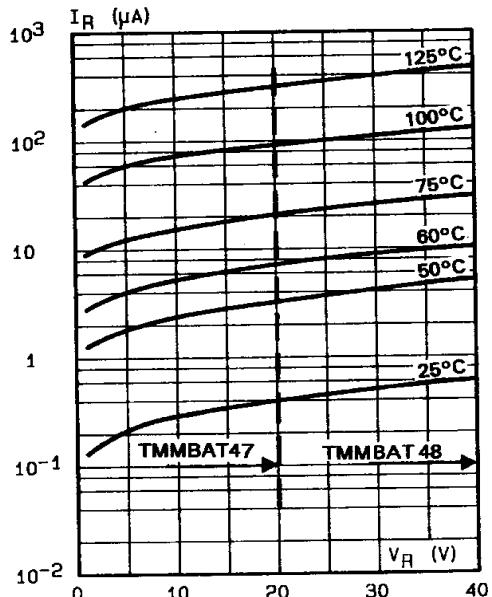
**Figure 2.** Forward current versus forward voltage (typical values).



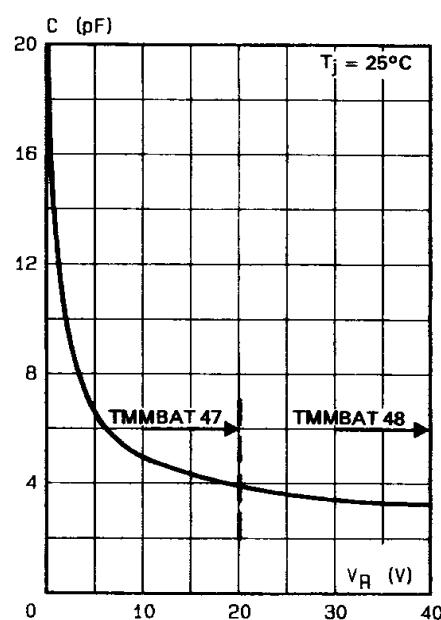
**Figure 3.** Reverse current versus junction temperature.



**Figure 4.** Reverse current versus continuous reverse voltage (typical values).

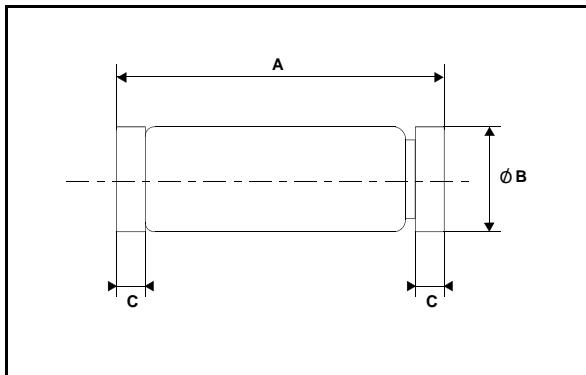


**Figure 5. Capacitance C versus reverse applied voltage  $V_R$  (typical values).**



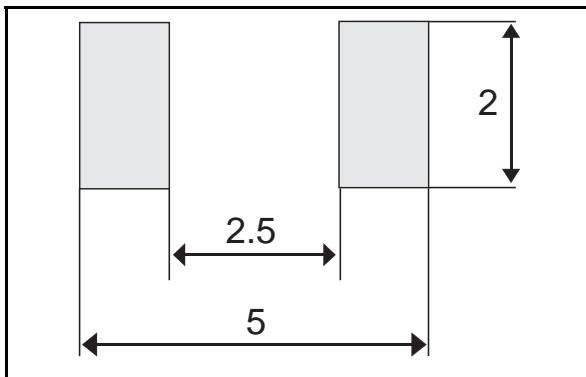
## PACKAGE MECHANICAL DATA

MINIMELF Glass



REF.	DIMENSIONS					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	3.30	3.40	3.6	0.130	0.134	0.142
B	1.59	1.60	1.62	0.063	0.063	0.064
C	0.40	0.45	0.50	0.016	0.018	0.020
D		1.50			0.059	

## FOOT PRINT DIMENSIONS (Millimeter)



Marking: ring at cathode end.  
Weight: 0.05g

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